

7.0V to 9.5V

0.001%(Typ)

+15dB to -79dB

Sound Processor with Built-in 2-band Equalizer **BD37515FS**

General Description

BD37515FS is a sound processor with built-in 2-band equalizer for car audio. The functions are 4ch stereo input selector, input-gain control, main volume, loudness, and 5ch fader volume. Moreover, its "Advanced switch circuit", which is an original ROHM technology, can reduce various switching noise (ex. No-signal, low frequency like 20Hz & large signal inputs). "Advanced switch" makes control of microcomputer easier, supporting the construction of a high quality car audio system.

Features

- Reduce switching noise of input gain control, mute, main volume, fader volume, bass, treble, loudness by using advanced switch circuit.
- Built-in 1 differential input selector and 3 single-ended input selectors
- Built-in ground isolation amplifier inputs, ideal for external stereo input.
- Built-in input gain controller reduces switching noise for volume of a portable audio input.
- Decrease the number of external components due to built-in 2-band equalizer filter, LPF for subwoofer, and loudness filter. Also, it is possible to control Q, Gv, fo of 2-band equalizer, fc of LPF for subwoofer and Gv of loudness using I²C BUS control.
- It is possible to adjust the gain of the bass and treble up to ±20dB with 1 dB step gain adjustment.
- It is equipped with output terminals of Subwoofer.
- Energy-saving design resulting in low current consumption, by utilizing the Bi-CMOS process. It has the advantage in quality over scaling down the power heat control of the internal regulators.
- Input terminals and output terminals are organized and separately laid out to keep the signal flow in one direction which results in simpler and smaller PCB lavout.
- It is possible to control the I²C BUS by 3.3V / 5V.

Key Specifications

- Power Supply Voltage Range:
- Circuit Current (No Signal): 38mA(Typ) Total harmonic Distortion 1:
- (FRONT, REAR) Total Harmonic Distortion 2: (SUBWOOFER)
- 0.002% (Typ) Maximum Input Voltage: 2.3Vrms (Typ) -100dB (Typ)
- Cross-talk Between Selectors:
- Volume Control Range: Output Noise Voltage1:
- (FRONT, REAR) 3.8µVrms (Typ) Output Noise Voltage2:
- 4.8µVrms (Typ) (SUBWOOFER) Residual Output Noise voltage: 1.8µVrms (Typ)
- -40°C to +85°C Operating Temperature Range:

Package

W(Typ) x D(Typ) x H(Max)

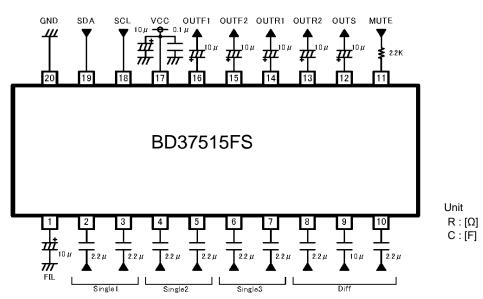


Applications

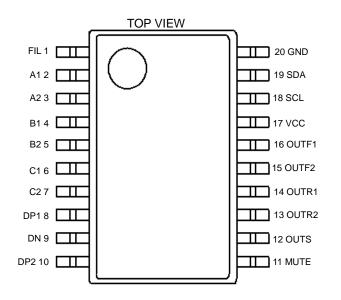
It is optimal for use in car audio systems. It can also be used for audio equipment of mini Compo, micro Compo, TV. etc.

OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

Typical Application Circuit



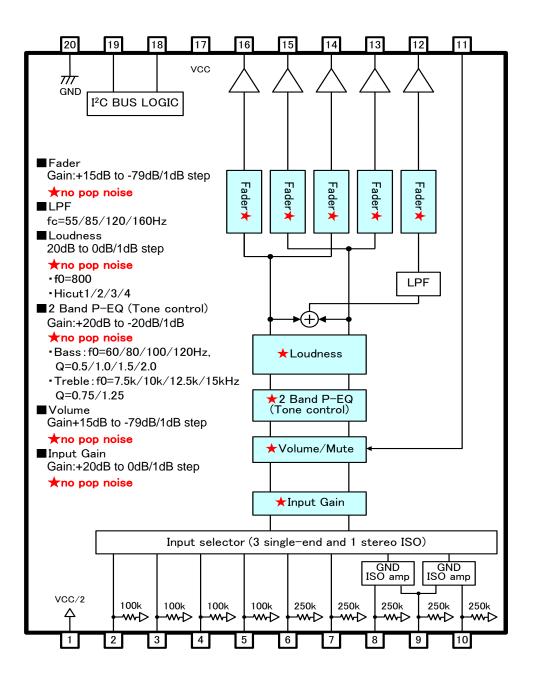
Pin Configuration



Pin Descriptions

Pin No.	Pin Name	Description	Pin No.	Pin Name	Description
1	FIL	VCC/2 terminal	11	MUTE	External compulsory mute terminal
2	A1	A input terminal of 1ch	12	OUTS	Subwoofer output terminal
3	A2	A input terminal of 2ch	13	OUTR2	Rear output terminal of 2ch
4	B1	B input terminal of 1ch	14	OUTR1	Rear output terminal of 1ch
5	B2	B input terminal of 2ch	15	OUTF2	Front output terminal of 2ch
6	C1	C input terminal of 1ch	16	OUTF1	Front output terminal of 1ch
7	C2	C input terminal of 2ch	17	VCC	Power supply terminal
8	DP1	D positive input terminal of 1ch	18	SCL	I ² C Communication clock terminal
9	DN	D negative input terminal	19	SDA	I ² C Communication data terminal
10	DP2	D positive input terminal of 2ch	20	GND	GND terminal

Block Diagram



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage	Vcc	10.0	V
Input Voltage	Vin	Vcc+0.3 to GND-0.3	V
Power Dissipation	Pd	0.94 ^(Note)	W
Storage Temperature	Tstg	-55 to +150	°C

(Note) This value derates by 7.5mW/²C for Ta=25°C or more when ROHM standard board is used. Thermal resistance θja = 133.3(°C/W)

ROHM Standard board

Size : 70 x 70 x 1.6(mm³)

Material : A FR4 grass epoxy board(3% or less of copper foil area)

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Power Supply Voltage	Vcc	7.0	-	9.5	V
Temperature	Topr	-40	-	+85	V

Electrical Characteristics

(Unless specified otherwise, Ta=25°C, V_{CC}=8.5V, f=1kHz, V_{IN}=1Vrms, Rg=600Ω, R_L=10kΩ, A input, Input gain 0dB, Mute OFF, Volume 0dB, Tone control 0dB, Loudness 0dB, LPF OFF, Fader 0dB)

				Limit			
BLOCK	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
	Circuit Current	lq	-	38	48	mA	No signal
	Voltage Gain	Gv	-1.5	0	+1.5	dB	Gv=20log(Vout/VIN)
	Channel Balance	СВ	-1.5	0	+1.5	dB	$CB = G_{V1}-G_{V2}$
	Total Harmonic Distortion 1 (FRONT,REAR)	THD+N1	-	0.001	0.05	%	V _{OUT} =1Vrms BW=400Hz-30KHz
	Total Harmonic Distortion 2 (SUBWOOFER)	THD+N2	-	0.002	0.05	%	V _{OUT} =1Vrms BW=400Hz-30KHz
RAL	Output Noise Voltage 1 (FRONT,REAR) *	V _{NO1}	-	3.8	15	μVrms	Rg = 0Ω BW = IHF-A
GENERAL	Output Noise Voltage 2 (SUBWOOFER) *	V _{NO2}	-	4.8	15	μVrms	Rg = 0Ω BW = IHF-A
	Residual Output Noise Voltage *	VNOR	-	1.8	10	μVrms	Fader = -∞dB Rg = 0Ω BW = IHF-A
	Cross-talk Between Channels *	СТС	-	-100	-90	dB	
	Ripple Rejection	RR	-	-70	-40	dB	f=1KHz V _{RR} =100mVrms RR=20log(V _{CC} IN/V _{OUT})
	Input Impedance(A,B)	RIN_S	70	100	130	kΩ	
~	Input Impedance (C,D)	R_{IN_D}	175	250	325	kΩ	
CTOF	Maximum Input Voltage	Vim	2.1	2.3	-	Vrms	Viм at THD+N(Vou⊤)=1% BW=400Hz-30KHz
INPUT SELECTOR	Cross-talk Between Selectors *	CTS	-	-100	-90	dB	$\begin{array}{l} Rg = 0\Omega \\ CTS = 20 log(V_{OUT}/V_{IN}) \\ BW = IHF-A \end{array}$
NUPL	Common Mode Rejection Ratio *	CMRR	50	65	-	dB	DP1 and DN input DP2 and DN input CMRR=20log(V _{IN} /V _{OUT}) BW = IHF-A
GAIN	Minimum Input Gain	GIN_MIN	-2	0	+2	dB	Input gain 0dB V _{IN} =100mVrms G _{IN} =20log(V _{OUT} /V _{IN})
INPUT (Maximum Input Gain	Gin_max	+18	+20	+22	dB	Input gain 20dB V _{IN} =100mVrms G _{IN} =20log(V _{OUT} /V _{IN})
	Gain Set Error	GIN_ERR	-2	0	+2	dB	GAIN=+1dB to +20dB

Electrical Characteristics - continued

(Unless specified otherwise, Ta=25°C, V_{CC}=8.5V, f=1kHz, V_{IN}=1Vrms, Rg=600Ω, R_L=10kΩ, A input, Input gain 0dB, Mute OFF, Volume 0dB, Tone control 0dB, Loudness 0dB, LPF OFF, Fader 0dB)

Mute OFF, Volume OdB, Tone control OdB, Loudness OdB, LPF OFF, Fader OdB) X Limit									
BLOCK	Parameter	Symbol	Min	Тур	Max	Unit	Conditions		
MUTE	Mute Attenuation *	Gmute	-	-105	-85	dB	Mute ON G _{MUTE} =20log(V _{OUT} /V _{IN}) BW = IHF-A		
	Maximum Gain	G _{V_MAX}	+13	+15	+17	dB	Volume = $15dB$ V _{IN} =100mVrms GV=20log(V _{OUT} /V _{IN})		
VOLUME	Maximum Attenuation *	Gv_min	-	-100	-85	dB	Volume = -∞dB GV=20log(V _{OUT} /V _{IN}) BW = IHF-A		
>	Attenuation Set Error 1	Gv_err1	-2	0	+2	dB	GAIN & ATT=+15dB to -15dB		
	Attenuation Set Error 2	Gv_err2	-3	0	+3	dB	ATT=-16dB to -47dB		
	Attenuation Set Error 3	Gv_err3	-4	0	+4	dB	ATT=-48dB to -79dB		
S	Maximum Boost Gain	GB_BST	+18	+20	+22	dB	GAIN=+20dB f=100Hz V _{IN} =100mVrms G _B =20log (V _{OUT} /V _{IN})		
BASS	Maximum Cut Gain	G _{B_CUT}	-22	-20	-18	dB	Gain=-20dB f=100Hz V _{IN} =2Vrms G _B =20log (V _{OUT} /V _{IN})		
	Gain Set Error	G _{B_ERR}	-2	0	+2	dB	Gain=+20dB to -20dB f=100Hz		
щ	Maximum Boost Gain	Gt_bst	+18	+20	+22	dB	Gain=+20dB f=10kHz V _{IN} =100mVrms G⊤=20log (V _{OUT} /V _{IN})		
TREBLE	Maximum Cut Gain	Gt_cut	-23	-20	-17	dB	GAIN=-20dB f=10kHz V _{IN} =2Vrms GT=20log (V _{OUT} /V _{IN})		
	Gain Set Error	G _{T_ERR}	-2	0	+2	dB	Gain=+20dB to -20dB f=10kHz		
ĸ	Maximum Boost Gain	G _{F_BST}	+13	+15	+17	dB	Fader=15dB V_{IN} =100mVrms G_F =20log(V_{OUT}/V_{IN})		
SUBWOOFER	Maximum Attenuation*	G _{F_MIN}	-	-100	-90	dB	Fader = -∞dB G _F =20log(V _{OUT} /V _{IN}) BW = IHF-A		
UB	Gain Set Error	Gf_err	-2	0	+2	dB	Gain=+1dB to +15dB		
\	Attenuation Set Error 1	G _{F_ERR1}	-2	0	+2	dB	ATT=0dB to -15dB		
ER	Attenuation Set Error 2	GF_ERR2	-3	0	+3	dB	ATT=-16dB to -47dB		
FADE	Attenuation Set Error 3	Gf_err3	-4	0	+4	dB	ATT=-48dB to -79dB		
Ľ	Output Impedance	Rout	-	-	50	Ω	V _{IN} =100mVrms		
	Maximum Output Voltage	Vом	2	2.2	-	Vrms	THD+N=1% BW=400Hz-30KHz		
LOUDNESS	Maximum Gain	Gl_max	+17	+20	+23	dB	Gain 20dB V _{IN} =100mVrms GL=20log(V _{OUT} /V _{IN})		
LOUE	Gain Set Error	Gl_err	-2	0	+2	dB	GAIN=+20dB to +1dB		

VP-9690A(Average value detection, effective value display) filter by Matsushita Communication is used for * measurement. Phase between input / output is same.

Typical Performance Curves

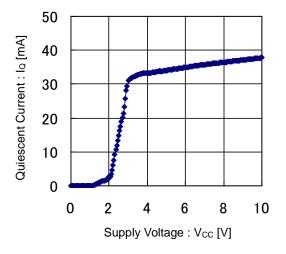
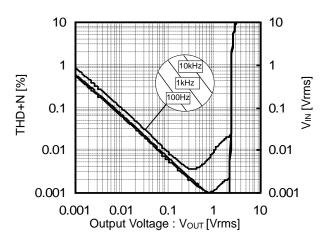


Figure 1. Quiescent Current vs Supply Voltage





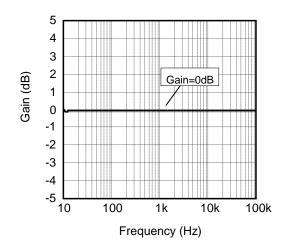
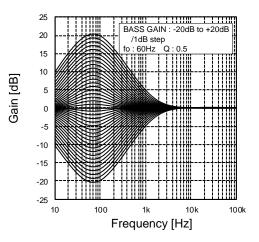


Figure 3. Gain vs Frequency



Typical Performance Curves - continued

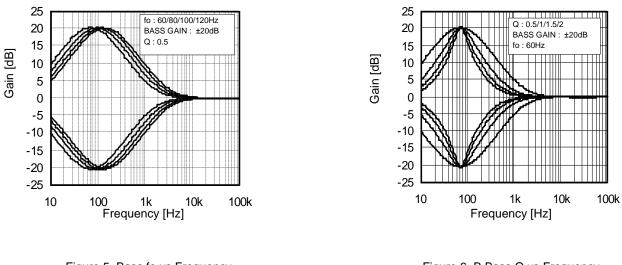
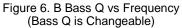
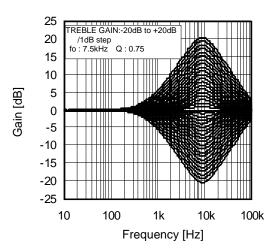


Figure 5. Bass fo vs Frequency (Bass fo is Changeable)







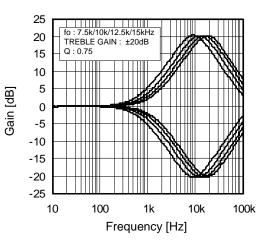
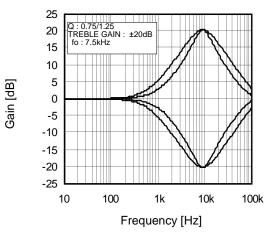
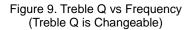
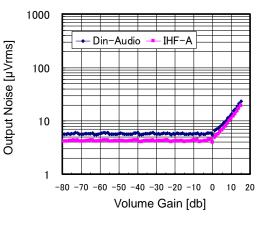


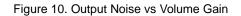
Figure 8. Treble fo vs Frequency (Treble fo is Changeable)

Typical Performance Curves - continued









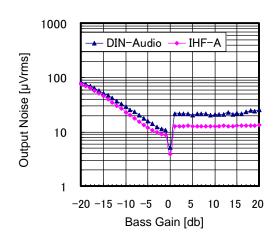


Figure 11. Output Noise vs Bass Gain

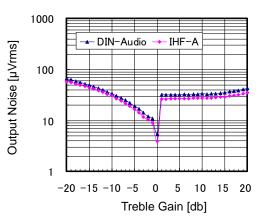


Figure 12. Output Noise vs Treble Gain

Typical Performance Curves - continued

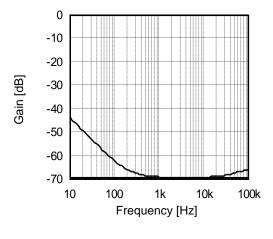
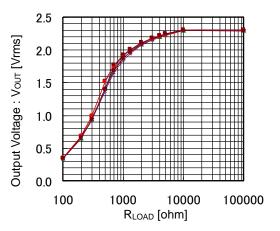
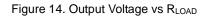


Figure 13. CMRR vs Frequency





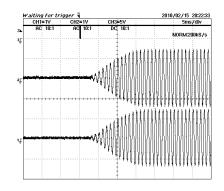


Figure 15. Advanced Switch 1

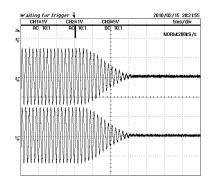


Figure 16. Advanced Switch 2

Timing Chart

Control Signal Specification

(1) Electrical Specifications and Timing for Bus Lines and I/O Stage

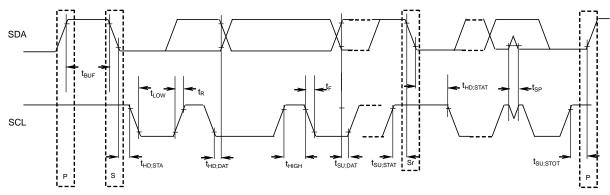


Figure 17. I²C-bus Signal Timing Diagram

Table 1 Characteristics of the SDA and SCL bus lines for I²C-bus devices (Unless specified otherwise, Ta=25°C, Vcc=8.5V)

	Parameter	Symbol	Fast-mod	e l²C-bus	Unit
	Faldineter	Symbol	Min	Max	Unit
1	SCL clock frequency	f scL	0	400	kHz
2	Bus free time between a STOP and START condition	t BUF	1.3	-	μS
3	Hold time (repeated) START condition. After this period, the first clock	t	0.6		
3	pulse is generated	thd;sta	0.0	-	μS
4	LOW period of the SCL clock	t∟ow	1.3	-	μS
5	HIGH period of the SCL clock	tнigн	0.6	-	μS
6	Set-up time for a repeated START condition	t su;sta	0.6	-	μS
7	Data hold time:	thd;dat	0.06 (Note)	-	μS
8	Data set-up time	tsu;dat	120	-	ns
9	Set-up time for STOP condition	tsu;sto	0.6	-	μS

All values referred to VIH Min and VIL Max Levels (see Table 2).

(Note) To avoid sending right after the fall-edge of SCL (VIH min of the SCL signal), the transmitting device should set a hold time of 300ns or more for the SDA signal.

For 7(t_{HD;DAT}), 8(t_{SU;DAT}), make the setup in which the margin is fully in.

Table 2 Characteristics of the SDA and SCL I/O stages for I²C-bus devices

	Parameter	Symbol	Fast-mod	Unit	
	Faldineter	Symbol	Min	Max	Unit
10	LOW level input voltage:	VIL	-0.3	+1	V
11	HIGH level input voltage:	VIH	2.3	5	V
12	Pulse width of spikes which must be suppressed by the input filter.	tsp	0	50	ns
13	LOW level output voltage: at 3mA sink current	V _{OL1}	0	0.4	V
14	Input current of each I/O pin with an input voltage between 0.4V and 4.5V.	lı –	-10	+10	μA

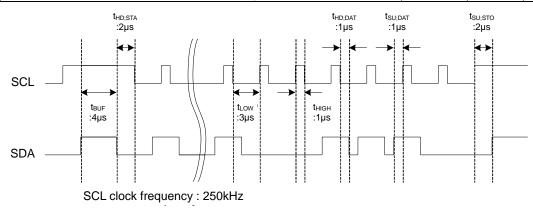


Figure 18. I²C Data Transmission Command Timing Diagram

(2) I²C BUS FORMAT

Ν	ISB LSB	MSB		LSB		MSB	L	SB			
S	Slave Address	Α	Select A	ddress	А		Data		Α	Р	
1bit	8bit	1bit	8	Bbit	1bit		8bit		1bit	1bit	
	S	= Sta	rt condition	(Recognitio	on of s	start bit)					
	Slave Address = Recognition of slave address. The first 7 bits correspond to the slave										e address.
	The least significant bit is "L" which corresponds to write mode.										
	A	= AC	KNOWLED	GE bit (Red	cognit	ion of ac	knowledge	ment)			
	Select Address										
	Data	= Da	ta on every	volume and	d tone	.					
	Р	= Sto	p condition	(Recognitio	on of s	stop bit)					

(3) <u>I²C BUS Interface Protocol</u>

(a) E	Basic format									
	S	Slave Addre	ess	Α	Select A	ddress	Α	Da	ta	Α	Р
_		MSB	LSB		MSB	LSB	Ν	/ISB	LSE	3	

(b)	Automatic Increment	(Se	elect Address increas	ses (+1)	accordin	g to	the number	of da	ata.)	
											Г

S	S Slave Address		А	Select Address		А	Data1		A Data2		А		DataN	A	F	,
1	//SB	LSB	ľ	MSB	LSB		MSB	LS	βB	MSB	SB	MS	SB L	SB		
		A 1 11			· · · ·			~								

(Example) ① Data1 shall be set as data of address specified by Select Address.

2 Data2 shall be set as data of address specified by Select Address +1. ③ DataN shall be set as data of address specified by Select Address +N-1.

(c) Configuration Unavailable for Transmission (In this case, only Select Address1 is set.)

S	Slave A	ddress	А	Select	Address1	А	Da	ata	А	Select	Address 2	Α	Da	ata	Α	Ρ
Ν	ИSB	LSB		MSB	LSB	Μ	ISB	LSE	3	MSB	LSE	8 M	SB	LS	βB	
	(Note	e) If anv	dat	a is transr	mitted as Se	elec	t Ad	dress	; 2 r	next to da	ata, it is reco	aniz	'ed			

data is transmitted as Select Address 2 next to data, it is reco as data, not as Select Address 2.

(4) Slave Address

Ν

I	MSB							LSB	
	A6	A5	A4	A3	A2	A1	A0	R/W	
	1	0	0	0	0	0	0	0	80H

(5) Select Address & Data

	Select	MSB			Da	ta			LSB	
Items	Address (hex)	D7	D6	D5	D4	D3	D2	D1	D0	
Initial setup 1	01	Advance d switch ON/OFF	0	of Input C	switch time Sain/Volume er/Loudness	0	0		ced switch of Mute	
Initial setup 2	02	LPF Phase 0°/180°	0	0 0 0 0 Subwoo			ofer LPF fc			
Initial setup 3	03	0	0	0	1	0	0	0	1	
Input Selector	05	0	0	0		In	put select	or	•	
Input gain	06	Mute ON/OFF	ON/OFF 0 0 Input Gain							
Volume gain	20			V	olume Gain /	Attenuatio	n			
Fader 1ch Front	28		Fader Gain / Attenuation							
Fader 2ch Front	29	Fader Gain / Attenuation								
Fader 1ch Rear	2A		Fader Gain / Attenuation							
Fader 2ch Rear	2B			F	ader Gain /	Attenuation	า			
Fader Subwoofer	2C			F	ader Gain /	Attenuation	า			
Bass setup	41	0	0	Ba	iss fo	0	0	Ba	ass Q	
Test mode 1	44	0	0	0	0	0	0	0	0	
Treble setup	47	0	0	Tre	ble fo	0	0	0	Treble Q	
Bass gain	51	Bass Boost/ Cut	0	0		I	Bass Gair	ı		
Test mode 2	54	1	0	0	0	0	0	0	0	
Treble gain	57	Treble Boost/ Cut	0	0	Treble Gain					
Loudness Gain	75	0	Loudne	ess Hicut	cut Loudness Gain					
System Reset	FE	1	0	0	0	0	0	0	1	
								Advar	nced switch	

Note

- 1. The Advanced Switch works in the latch part while changing from one function to another.
- 2. Upon continuous data transfer, the Select Address rolls over because of the automatic increment function, as shown below.

- 3. For the function of Input Selector etc, Advanced Switch is not used. Therefore, please apply mute on the set side when changing these settings.
- 4. When using mute function of this IC at the time of changing input selector, please switch mute ON/OFF while waiting for advanced-mute time.

Select address 01 (hex)

Time	MSB Advanced switch time of Mute LSB									
Time	D7	D6	D5	D4	D3	D2	D1	D0		
0.6msec	Advanced		Advonced	owitch time			0	0		
1.0msec	Advanced Switch	0	Advanced s		0	0	0	1		
1.4msec	ON/OFF	0		in/Volume	0	0	1	0		
3.2msec			Tone/Fader/Loudness				1	1		

Time	MSB	Advanced switch time of Input gain/Volume/Tone/Fader/Loudness								
	D7	D6	D5	D4	D3	D2	D1	D0		
4.7 msec			0	0						
7.1 msec	Advanced	0	0	1	0	0	Advanced switc Time of Mute			
11.2 msec	Switch	0	1	0						
14.4 msec	UN/OFF		1	1						

Mode	MSB	MSB Advanced switch ON/OFF								
Mode	D7	D6	D5	D4	D3	D2	D1	D0		
OFF	0	0	Advanced switch time of Input gain/Volume Tone/Fader/Loudness		0	0	Advanced switch Time of Mute			
ON	1	0			0	0				

f.a.	MSB	MSB Subwoofer LPF fc									
fc	D7	D7 D6 D5 D4 D3 D2 D1									
OFF						0	0	0			
55Hz						0	0	1			
85Hz	LPF	0	0	0	0	0	1	0			
120Hz	Phase	0	0	0	0	0	1	1			
160Hz						1	0	0			
Prohibition							Other setting	1			

Phase	MSB	LPF Phase							
	D7	D6	D5	D4	D3	D2	D1	D0	
0°	0	0	0	0	0	Subwoofer LPF fc		fo	
180°	1	0	0	0	0			- 10	

Select address 05(he	x)							
Mode	MSB		I	nput S	electo	r		LSB
Mode	D7	D6	D5	D4	D3	D2	D1	D0
Initial					0	0	0	0
A					0	0	0	1
В					0	0	1	0
С	0	0	0	0	0	0	1	1
D diff					0	1	1	1
Input SHORT					1	0	0	1
Prohibition						Other	setting	

Input SHORT : The input impedance of each input terminal is lowered from $100k\Omega(TYP)$ to $6 k\Omega(TYP)$. (For quick charge of coupling capacitor)

: Initial condition

Select address 06 (hex)

Coin	MSB			Inpu	ut Gain			LSB		
Gain	D7	D6	D5	D4	D3	D2	D1	D0		
0dB				0	0	0	0	0		
1dB				0	0	0	0	1		
2dB				0	0	0	1	0		
3dB				0	0	0	1	1		
4dB				0	0	1	0	0		
5dB				0	0	1	0	1		
6dB				0	0	1	1	0		
7dB				0	0	1	1	1		
8dB				0	1	0	0	0		
9dB				0	1	0	0	1		
10dB				0	1	0	1	0		
11dB	Mute	_		0	1	0	1	1		
12dB	ON/OFF	0	0	0	1	1	0	0		
13dB						0	1	1	0	1
14dB				0	1	1	1	0		
15dB				0	1	1	1	1		
16dB				1	0	0	0	0		
17dB				1	0	0	0	1		
18dB				1	0	0	1	0		
19dB				1	0	0	1	1		
20dB				1	0	1	0	0		
				1	1	0	1	1		
Prohibition				:	•	•••	•••	•••		
				1	1	1	1	1		

Mada	MSB	Mute ON/OFF LSB								
Mode	D7									
OFF	0	0	0			Innut Coin				
ON	1	0	0 Input Gain							

Select address 20, 28, 29, 2A, 2B, 2C (hex)

Gain & ATT	MSB		Vol. Fader Gain / Attenuation							
Gairi & Al I	D7	D6	D5	D4	D3	D2	D1	D0		
	0	0	0	0	0	0	0	0		
	0	0	0	0	0	0	0	1		
Prohibition	:	:	:	:	:	:	:	:		
	0	1	1	1	0	0	0	0		
15dB	0	1	1	1	0	0	0	1		
14dB	0	1	1	1	0	0	1	0		
13dB	0	1	1	1	0	0	1	1		
:	:	:	:	:	:	:	:	:		
-77dB	1	1	0	0	1	1	0	1		
-78dB	1	1	0	0	1	1	1	0		
-79dB	1	1	0	0	1	1	1	1		
	1	1	0	1	0	0	0	0		
Prohibition	:	:	:	:	:	:	:	:		
	1	1	1	1	1	1	1	0		
-∞dB	1	1	1	1	1	1	1	1		

: Initial condition

LSB D0 0

Select address 41(hex)

Q factor	MSB Bass Q Factor								
	D7	D6	D5	D4	D3	D2	D1	D0	
0.5					0	0	0	0	
1.0	0	0	Poo	a fa			0	1	
1.5	0	0	Das	ss fo			1	0	
2.0							1	1	

fo	MSB	Bass fo							
fO	D7	D6	D5	D4	D3	D2	D1	D0	
60Hz			0	0					
80Hz	0	0	0	1	0	0	Bas	SS	
100Hz	0	0	1	0	0	0	Bas Q fac	ctor	
120Hz			1	1					

Select address 47 (hex	<)							
Q factor	MSB			Treble C	Q Factor			
	D7	D6	D5	D4	D3	D2	D1	Ι
0.75	0	0	Trob	le fo	0	0	0	
1.25	0	0	Tieb		0	0	0	
fo	MSB			Treb	le fo			

fo	MSB			Treb	le fo			LSB
fo	D7	D6	D5	D4	D3	D2	D1	D0
7.5kHz			0	0				
10kHz	0	0	0	1		0	0	Treble
12.5kHz	0	0	1	0	0	0	0	Treble Q factor
15kHz			1	1				

: Initial condition

Select address 51,	MSB			Bass/ Tre	ble Gain			LSB
Gain	D7	D6	D5	Dass/ 116	D3	D2	D1	D0
0dB		00	05	0	0	0	0	0
1dB				0	0	0	0	1
2dB				0	0	0	1	0
3dB				0	0	0	1	1
4dB				0	0	1	0	0
5dB				0	0	1	0	1
6dB				0	0	1	1	0
7dB				0	0	1	1	1
8dB				0	1	0	0	0
9dB				0	1	0	0	1
10dB				0	1	0	1	0
11dB	Bass/			0	1	0	1	1
12dB	Treble	0	0	0	1	1	0	0
13dB	Boost	0	0	0	1	1	0	1
14dB	/cut			0	1	1	1	0
15dB				0	1	1	1	1
16dB				1	0	0	0	0
17dB				1	0	0	0	1
18dB				1	0	0	1	0
19dB				1	0	0	1	1
20dB				1	0	1	0	0
				1	0	1	0	1
Drabibition				:	:	:	:	:
Prohibition				1	1	1	1	0
				1	1	1	1	1
	MSB			Bass/ Treble	e Boost/Cut			LSB
Mode	D7	D6	D5	D4000, 11000	D3	D2	D1	D0
Boost	0							20
Cut	1	0	0		Ba	ss/Treble G	ain	

: Initial condition

Select address 75 (hex)

Mada	MSB		Loudness Hicut							
Mode	D7	D6	D5	D4	D3	D2	D1	D0		
Hicut1		0	0							
Hicut2		0	1			audaaaa Cai	n			
Hicut3	0	1	0		L	oudness Gai	n			
Hicut4		1	1							

Gain		MSB Loudness Gain								
Gain	D7	D6	D5	D4	D3	D2	D1	D0		
0dB			•	0	0	0	0	0		
1dB				0	0	0	0	1		
2dB				0	0	0	1	0		
3dB				0	0	0	1	1		
4dB				0	0	1	0	0		
5dB				0	0	1	0	1		
6dB				0	0	1	1	0		
7dB				0	0	1	1	1		
8dB				0	1	0	0	0		
9dB				0	1	0	0	1		
10dB				0	1	0	1	0		
11dB				0	1	0	1	1		
12dB	0	Loudne	ss Hicut	0	1	1	0	0		
13dB				0	1	1	0	1		
14dB				0	1	1	1	0		
15dB				0	1	1	1	1		
16dB				1	0	0	0	0		
17dB				1	0	0	0	1		
18dB				1	0	0	1	0		
19dB				1	0	0	1	1		
20dB]			1	0	1	0	0		
				1	0	1	0	1		
Prohibition					:	:	:	:		
				1	1	1	1	1		

: Initial condition

(6) <u>About Power ON Reset</u> Built-in IC initialization is made during power ON of the supply voltage. Please send initial data to all addresses at supply voltage on. And please turn ON mute at the set side until this initial data is sent.

Deremeter	Quarkal		Limit		1 1 14	Conditions		
Parameter	Symbol	Min	Тур	Max	Unit	Conditions		
Rise Time of VCC	t _{RISE}	33	-	-	µsec	V_{CC} rise time from 0V to 5V		
VCC Voltage of Release Power ON Reset	VPOR	-	4.1	-	V			

(7) About External Compulsory Mute Terminal

It is possible to force mute externally by setting an input voltage to the MUTE terminal.

Mute Voltage Condition	Mode
GND to 1.0V	MUTE ON
2.3V to V _{CC}	MUTE OFF

Establish the voltage of MUTE in the condition to be defined.

Application Information

1. Function and Specifications

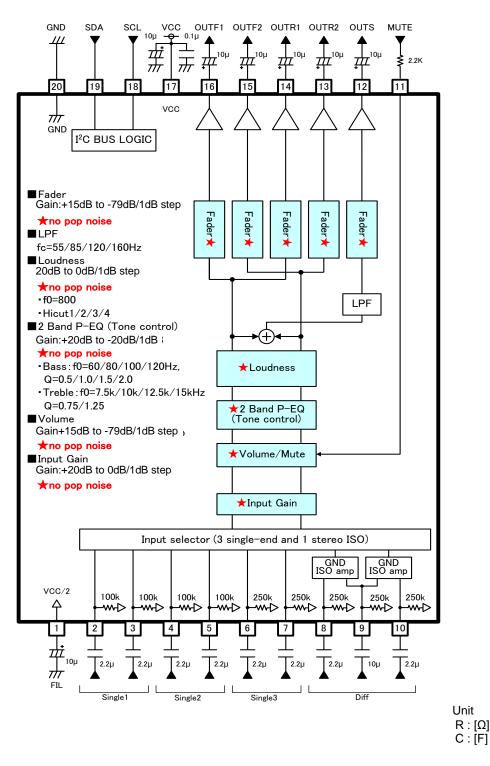
Function	Specification	S
Input selector	Stereo 3 input Differential 1 input	
Input gain	 +20dB to 0dB (1dB step) 	
input gain	Possible to use "Advanced switch" for prevention of sw	itching noise.
Mute	Possible to use "Advanced switch" for prevention of sw	itching noise.
Volume	 +15dB to -79dB (1dB step), -∞dB 	
voluitie	Possible to use "Advanced switch" for prevention of sw	itching noise.
Bass	 +20dB to -20dB (1dB step) 	• Q=0.5, 1, 1.5, 2
Dass	 Possible to use "Advanced switch" at changing gain 	• fo=60, 80, 100, 120Hz
Treble	 +20dB to -20dB (1dB step) 	• Q=0.75, 1.25
TEDIE	 Possible to use "Advanced switch" at changing gain 	 fo=7.5k, 10k, 12.5k, 15kHz
Fader	 +15dB to -79dB(1dB step), -∞dB 	
	Possible to use "Advanced switch" for prevention of sw	itching noise.
Loudness	20dB to 0dB(1dB step) fo=800Hz	
Loudness	Possible to use "Advanced switch" for prevention of sw	itching noise.
LPF	fc=55/85/120/160Hz, pass Phase shift (0°/180	°)

2. Volume / Fader Volume Attenuation Data

2.	volume /	rader	voiu	me A	ttenua	ation	Data	-						-	-	-		
	(dB)	D7	D6	D5	D4	D3	D2	D1	D0	(dB)	D7	D6	D5	D4	D3	D2	D1	D0
	+15	0	1	1	1	0	0	0	1	-33	1	0	1	0	0	0	0	1
	+14	0	1	1	1	0	0	1	0	-34	1	0	1	0	0	0	1	0
	+13	0	1	1	1	0	0	1	1	-35	1	0	1	0	0	0	1	1
	+12	0	1	1	1	0	1	0	0	-36	1	0	1	0	0	1	0	0
	+11	0	1	1	1	0	1	0	1	-37	1	0	1	0	0	1	0	1
	+10	0	1	1	1	0	1	1	0	-38	1	0	1	0	0	1	1	0
	+9	0	1	1	1	0	1	1	1	-39	1	0	1	0	0	1	1	1
	+8	0	1	1	1	1	0	0	0	-40	1	0	1	0	1	0	0	0
	+7	0	1	1	1	1	0	0	1	-41	1	0	1	0	1	0	0	1
	+6	0	1	1	1	1	0	1	0	-42	1	0	1	0	1	0	1	0
	+5	0	1	1	1	1	0	1	1	-43	1	0	1	0	1	0	1	1
	+4	0	1	1	1	1	1	0	0	-44	1	0	1	0	1	1	0	0
	+3	0	1	1	1	1	1	0	1	-45	1	0	1	0	1	1	0	1
	+2	0	1	1	1	1	1	1	0	-46	1	0	1	0	1	1	1	0
	+1	0	1	1	1	1	1	1	1	-47	1	0	1	0	1	1	1	1
	0	1	0	0	0	0	0	0	0	-48	1	0	1	1	0	0	0	0
	-1	1	0	0	0	0	0	0	1	-49	1	0	1	1	0	0	0	1
	-2	1	0	0	0	0	0	1	0	-50	1	0	1	1	0	0	1	0
	-3	1	0	0	0	0	0	1	1	-51	1	0	1	1	0	0	1	1
	-4	1	0	0	0	0	1	0	0	-52	1	0	1	1	0	1	0	0
	-5	1	0	0	0	0	1	0	1	-53	1	0	1	1	0	1	0	1
	-6	1	0	0	0	0	1	1	0	-54	1	0	1	1	0	1	1	0
	-7	1	0	0	0	0	1	1	1	-55	1	0	1	1	0	1	1	1
	-8	1	0	0	0	1	0	0	0	-56	1	0	1	1	1	0	0	0
	-9	1	0	0	0	1	0	0	1	-57	1	0	1	1	1	0	0	1
	-10	1	0	0	0	1	0	1	0	-58	1	0	1	1	1	0	1	0
	-11	1	0	0	0	1	0	1	1	-59	1	0	1	1	1	0	1	1
	-12	1	0	0	0	1	1	0	0	-60	1	0	1	1	1	1	0	0
	-13	1	0	0	0	1	1	0	1	-61	1	0	1	1	1	1	0	1
	-14	1	0	0	0	1	1	1	0	-62	1	0	1	1	1	1	1	0
	-15	1	0	0	0	1	1	1	1	-63	1	0	1	1	1	1	1	1
	-16	1	0	0	1	0	0	0	0	-64	1	1	0	0	0	0	0	0
	-17	1	0	0	1	0	0	0	1	-65	1	1	0	0	0	0	0	1
	-18	1	0	0	1	0	0	1	0	-66	1	1	0	0	0	0	1	0
	-19	1	0	0	1	0	0	1	1	-67	1	1	0	0	0	0	1	1
	-20	1	0	0	1	0	1	0	0	-68	1	1	0	0	0	1	0	0
	-21	1	0	0	1	0	1	0	1	-69	1	1	0	0	0	1	0	1
	-22	1	0	0	1	0	1	1	0	-70	1	1	0	0	0	1	1	0
	-23	1	0	0	1	0	1	1	1	-71	1	1	0	0	0	1	1	1
	-24	1	0	0	1	1	0	0	0	-72	1	1	0	0	1	0	0	0
	-25	1	0	0	1	1	0	0	1	-73	1	1	0	0	1	0	0	1
	-26	1	0	0	1	1	0	1	0	-74	1	1	0	0	1	0	1	0
	-27	1	0	0	1	1	0	1	1	-75	1	1	0	0	1	0	1	1
	-28	1	0	0	1	1	1	0	0	-76	1	1	0	0	1	1	0	0
F	-29	1	0	0	1	1	1	0	1	-77	1	1	0	0	1	1	0	1
┢	-30	1	0	0	1	1	1	1	0	-78	1	1	0	0	1	1	1	0
┢	-31	1	0	0	1	1	1	1	1	-79	1	1	0	0	1	1	1	1
┢	-32	1	0	1	0	0	0	0	0	-∞	1	1	1	1	1	1	1	1
L	02		0		0	0	0	0	0									

: Initial condition

3. Application Circuit



Notes on wiring

- ① Please connect the decoupling capacitor of the power supply in the shortest possible distance to GND.
- ② GND lines should be one-point connected.
- ③ Wiring pattern of Digital should be away from that of Analog unit and cross-talk should not be acceptable.
- (4) SCL and SDA lines of I²C BUS should not be parallel if possible.
- The lines should be shielded, if they are adjacent to each other.
- (5) Analog input lines should not be parallel if possible. The lines should be shielded, if they are adjacent to each other.

Power Dissipation

About the thermal design of the IC

Characteristics of an IC have a great deal to do with the temperature at which it is used, and exceeding absolute maximum ratings may degrade and destroy the device. Careful consideration must be given to the heat of the IC from the two standpoints of immediate damage and long-term reliability of operation.

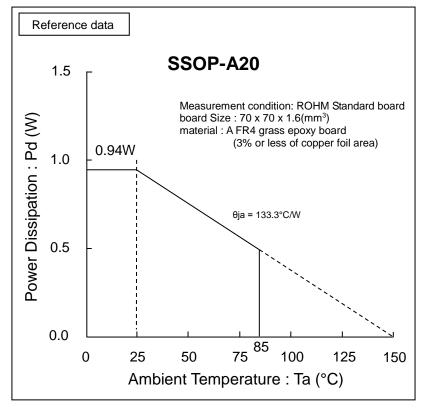


Figure 19. Temperature Derating Curve

(Note) Values are actual measurements and are not guaranteed.

Power dissipation values vary according to the board on which the IC is mounted

I/O Equivalent Circuits

Termina No.	I Terminal Name	Terminal voltage	Equivalent Circuit	Terminal Description
2 3 4 5	A1 A2 B1 B2	4.25	VCC Z VCC VCC VCC VO Z VO VO VO VO VO VO VO VO VO VO	A terminal for signal input. The input impedance is 100kΩ(typ).
6 7	C1 C2	4.25		A terminal for signal input. The input impedance is 250kΩ(typ).
8 9 10	DP1 DN DP2	4.25	VCC	Input terminal available to Single/Differential mode. The input impedance is 250kΩ(typ).
11	MUTE	_	VCC	A terminal for external compulsory mute. If terminal voltage is High level, the mute is OFF. And if the terminal voltage is Low level, the mute is on.
12 13 14 15 16	OUTS OUTR2 OUTR1 OUTF2 OUTF1	4.25	VCC	A terminal for fader and Subwoofer output.

Values in the pin explanation and input/output equivalent circuit are reference values only and are not guaranteed.

I/O Equivalent Circuits - continued

Te	erminal No.	Terminal Name	Terminal voltage	Equivalent Circuit	Terminal Description
	17	VCC	8.5		Power supply terminal.
	18	SCL		VCC	
		001			A terminal for clock input of I ² C BUS communication.
				GND T.65V	
	19	SDA	-	VCC	A terminal for data input of I ² C BUS communication.
	20	GND	0		Ground terminal.
	1	FIL	4.25	VCC 50k GND GND	1/2 VCC terminal. Voltage for reference bias of analog signal system. The simple precharge circuit and simple discharge circuit for an external capacitor are built in.

Values in the pin explanation and input/output equivalent circuit are reference values only and are not guaranteed.

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

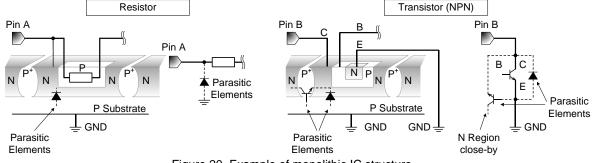
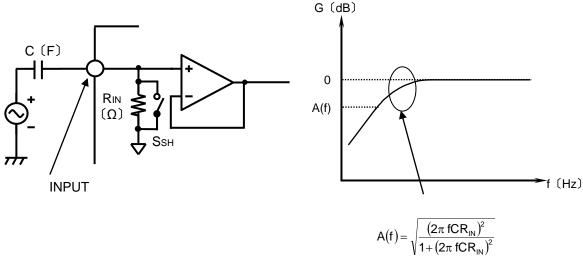


Figure 20. Example of monolithic IC structure

13. About a Signal Input Part

(a) About Input Coupling Capacitor Constant Value

In the input signal terminal, please decide the constant value of the input coupling capacitor C(F) that would be sufficient to form an RC characterized HPF with input impedance $R_{IN}(\Omega)$ inside the IC.



(b) About the Input Selector SHORT

SHORT mode is the command which makes switch S_{SH} =ON of input selector part so that the input impedance R_{IN} of all terminals becomes small. Switch S_{SH} is OFF when SHORT command is not selected. The constant time brought about by the small resistance inside and the capacitor outside the LSI becomes small when this command is used. The charge time of the capacitor becomes short. Since SHORT mode turns ON the switch of S_{SH} and makes it low impedance, please use it at no signal condition.

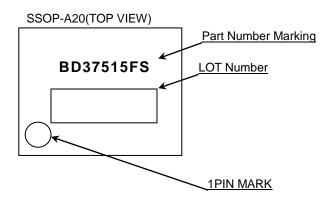
14. About Mute Terminal(Pin 11) when power supply is OFF

There should be no applied voltage across the Mute terminal (Pin 11) when power-supply is OFF. A resistor (about $2.2k\Omega$) should be connected in series to Mute terminal in case a voltage is supplied to Mute terminal. (Please refer Application Circuit Diagram.)

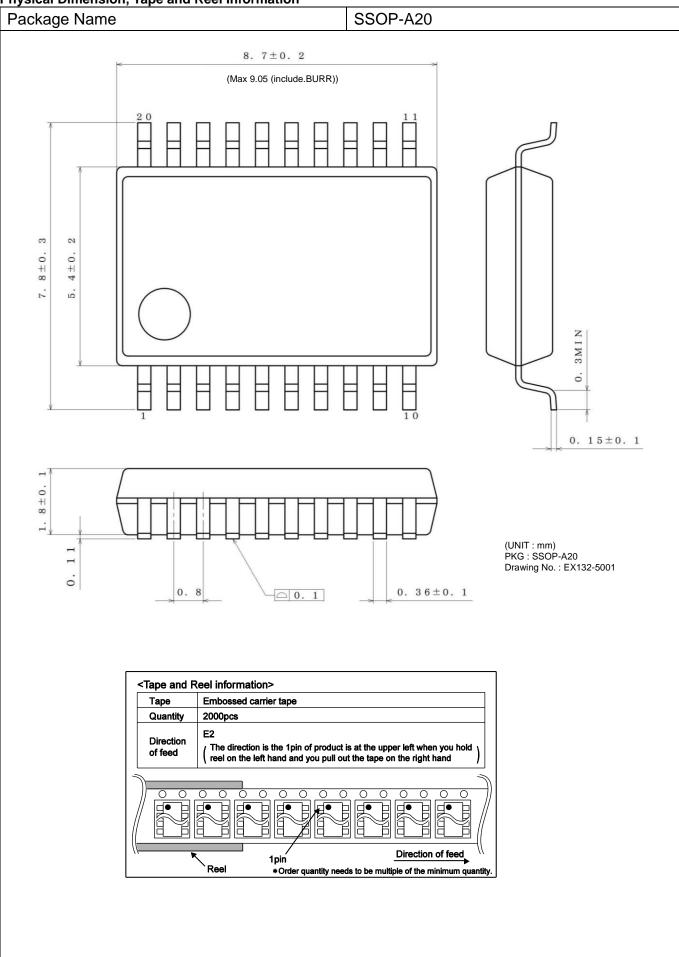
Ordering Information



Marking Diagram



Physical Dimension, Tape and Reel Information



Revision History

Date	Revision	Changes
16.Dec.2015	001	New Release

Notice

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(Note1) Medical Equipment Classification of the Specific Applications

JAPAN		USA	EU	CHINA	
			CLASS II b		
	CLASSⅣ	CLASSⅢ	CLASSⅢ	CLASSⅢ	

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 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

Precaution Regarding Intellectual Property Rights

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
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- 1. Before you use our Products, you are requested to care fully read this document and fully understand its contents. ROHM shall not be in an y way responsible or liable for failure, malfunction or accident arising from the use of a ny ROHM's Products against warning, caution or note contained in this document.
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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
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Как с нами связаться

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